

LOW EMI CLOCK GENERATOR

ICS180-51

Description

The ICS180-51 generates a low EMI output clock from a clock or crystal input. The device uses IDT's proprietary mix of analog and digital Phase-Locked Loop (PLL) technology to spread the frequency spectrum of the output, thereby reducing the frequency amplitude peaks by several dB.

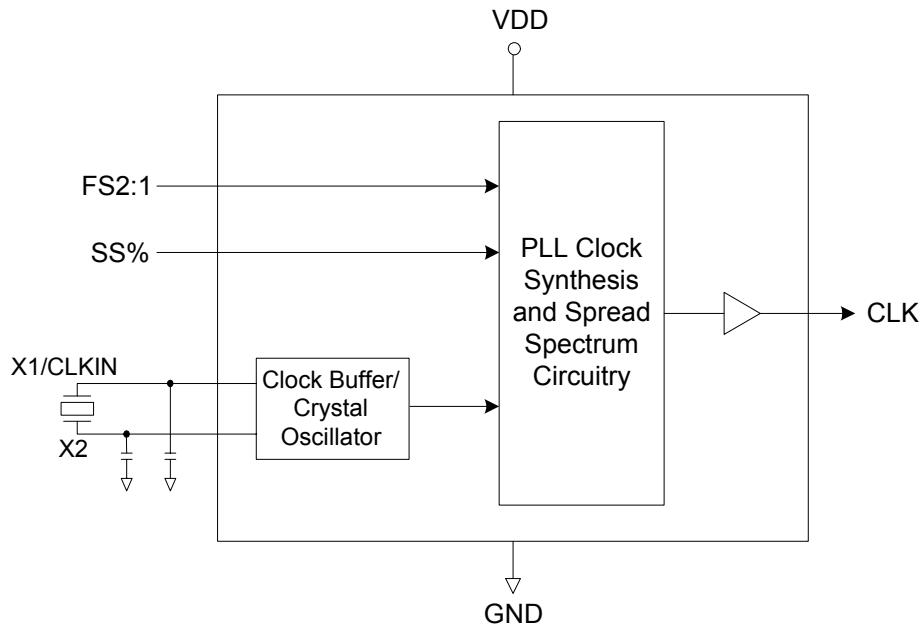
The ICS180-51 offers center spread selection of +/-0.625% and +/-1.875%. Refer to the MK1714-01/02 for the widest selection of input frequencies and multipliers.

IDT offers a complete line of EMI reducing clock generators. Consult us when you need to remove crystals and oscillators from your board.

Features

- Pin and function compatible to Cypress W180-51
- Packaged in 8-pin SOIC
- Provides a spread spectrum output clock
- Accepts a clock input and provides same frequency dithered output
- Input frequency of 8 to 28 MHz
- Peak reduction by 7dB - 14dB typical on 3rd - 19th odd harmonics
- Spread percentage selection for +/-0.625% and +/-1.875%
- Operating voltage of 3.3 V and 5 V
- Advanced, low-power CMOS process

Block Diagram



Pin Assignment



Spread Spectrum Select Table

SS% (Pin 4)	Spread Direction	Spread Percentage (%)
0	Center	+/-0.625%
1	Center	+1.875%

0 = connect to GND

1 = connect directly to VDD

Note: SS% pin has an internal pull-up resistor

Frequency Range Selection Table

FS2 (Pin 8)	FS1 (Pin 7)	Frequency Range Selection (MHz)
0	0	8-10
0	1	10-15
1	0	15-18
1	1	18-28

Pin Descriptions

Pin Number	Pin Name	Pin Type	Pin Description
1	X1/CLKIN	Input	Crystal or Clock Input.
2	X2	Output	Crystal output. Float for a clock input.
3	GND	Power	Connect to ground.
4	SS%	Input	Select pin for spread amount. See table above. Internal pull-up resistor.
5	CLKOUT	Output	Spread spectrum clock output per table above.
6	VDD	Power	Connect to 3.3 V or 5 V.
7	FS1	Input	Select pin for input frequency. See table above. Internal pull-up resistor.
8	FS2	Input	Select pin for input frequency. See table above. Internal pull-up resistor.

External Components

The ICS180-51 requires a minimum number of external components for proper operation.

Decoupling Capacitor

A decoupling capacitor of 0.01 μ F must be connected between VDD and GND on pins 6 and 3, as close to these pins as possible. For optimum device performance, the decoupling capacitor should be mounted on the component side of the PCB. Avoid the use of vias in the decoupling circuit.

Series Termination Resistor

When the PCB trace between the clock output and the load is over 1 inch, series termination should be used. To series terminate a 50 Ω trace (a commonly used trace impedance) place a 33 Ω resistor in series with the clock line, as close to the clock output pin as possible. The nominal impedance of the clock output is 20 Ω .

value of these capacitors is given by the following equation:

Absolute Maximum Ratings

Stresses above the ratings listed below can cause permanent damage to the ICS180-51. These ratings, which are standard values for IDT commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

Item	Rating
Supply Voltage, VDD	7 V
All Inputs and Outputs	-0.5 V to VDD+0.5 V
Ambient Operating Temperature	0 to +70° C
Storage Temperature	-65 to +150° C
Junction Temperature	125° C
Soldering Temperature	260° C

Recommended Operation Conditions

Parameter	Min.	Typ.	Max.	Units
Ambient Operating Temperature	0		+70	° C
Power Supply Voltage (measured in respect to GND)	+3.135		+5.5	V

PCB Layout Recommendations

For optimum device performance and lowest output phase noise, the following guidelines should be observed.

- 1) The 0.01 μ F decoupling capacitor should be mounted on the component side of the board as close to the VDD pin as possible. No vias should be used between the decoupling capacitor and VDD pin. The PCB trace to VDD pin should be kept as short as possible, as should the PCB trace to the ground via.
- 2) To minimize EMI, the 33 Ω series termination resistor (if needed) should be placed close to the clock output.
- 3) An optimum layout is one with all components on the same side of the board, minimizing vias through other signal layers. Other signal traces should be routed away from the ICS180-51. This includes signal traces just underneath the device, or on layers adjacent to the ground plane layer used by the device.

DC Electrical Characteristics

Unless stated otherwise, **VDD = 3.3 V ±5%**, Ambient Temperature 0 to +70°C

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Operating Voltage	VDD		3.135		3.465	V
Supply Current	IDD	No load		18	32	mA
Input High Voltage	V _{IH}		2.4			V
Input Low Voltage	V _{IL}				0.8	V
Output High Voltage	V _{OH}	I _{OH} = -4 mA	VDD-0.4			V
Output High Voltage	V _{OH}	I _{OH} = -15 mA	2.4			V
Output Low Voltage	V _{OL}	I _{OL} = 15 mA			0.4	V
Input Capacitance	C _{IN}			5	7	pF
Output Impedance	R _{out}			25		ohms
Input Pull-up Resistor				500		KΩ
Power-up Time		First locked clock cycle after steady power			5	ms

Unless stated otherwise, **VDD = 5 V, ±10%**, Ambient Temperature 0 to +70°C

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Operating Voltage	VDD		4.5	5	5.5	V
Supply Current	IDD	No load		30	50	mA
Input High Voltage	V _{IH}		0.7VDD			V
Input Low Voltage	V _{IL}				0.15VDD	V
Output High Voltage	V _{OH}	I _{OH} = -24 mA	2.4			V
Output Low Voltage	V _{OL}	I _{OL} = 24 mA			0.4	V
Output Impedance	R _{out}			20		ohms
Input Capacitance	C _{IN}			5	7	pF
Input Pull-up Resistor				500		KΩ
Power-up Time		First locked clock cycle after steady power			5	ms

AC Electrical Characteristics

Unless stated otherwise, **VDD = 3.3 V±5% or 5 V±10%**, Ambient Temperature 0 to +70° C, $C_L=15$ pf

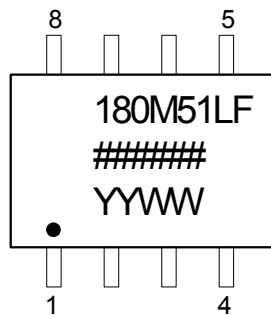
Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Input/Output Clock Frequency			8		28	MHz
Input Clock Duty Cycle		Time above VDD/2	40		60	%
Output Clock Duty Cycle		Note 1	40	50	60	%
Output Rise Time	t_{OR}	0.8 to 2.4 V, note 1		2	5	ns
Output Fall Time	t_{OF}	2.4 to 0.8 V, note 1		2	5	ns
Jitter		Cycle-to-cycle		250	300	ps

Note 1: Measured with 15 pF load

Thermal Characteristics

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Thermal Resistance Junction to Ambient	θ_{JA}	Still air		150		°C/W
	θ_{JA}	1 m/s air flow		140		°C/W
	θ_{JA}	3 m/s air flow		120		°C/W
Thermal Resistance Junction to Case	θ_{JC}			40		°C/W

Marking Diagram



Notes:

- ##### is the lot number.
- YYWW is the last two digits of the year and week that the part was assembled.
- “LF” denotes Pb (lead) free package.
- Bottom marking: country of origin.

Package Outline and Package Dimensions (8-pin SOIC, 150 Mil. Body)

Package dimensions are kept current with JEDEC Publication No. 95



Ordering Information

Part / Order Number	Marking	Shipping packaging	Package	Temperature
180M-51LF	see page 5	Tubes	8-pin SOIC	0 to +70° C
180M-51LFT		Tape and Reel	8-pin SOIC	0 to +70° C

“LF” denotes Pb free packaging.

While the information presented herein has been checked for both accuracy and reliability, IDT assumes no responsibility for either its use or for the infringement of any patents or other rights of third parties, which would result from its use. No other circuits, patents, or licenses are implied. This product is intended for use in normal commercial applications. Any other applications such as those requiring extended temperature range, high reliability, or other extraordinary environmental requirements are not recommended without additional processing by IDT. IDT reserves the right to change any circuitry or specifications without notice. IDT does not authorize or warrant any IDT product for use in life support devices or critical medical instruments.

Innovate with IDT and accelerate your future networks. Contact:

www.IDT.com

For Sales

800-345-7015
408-284-8200
Fax: 408-284-2775

For Tech Support

www.idt.com/go/clockhelp

Corporate Headquarters

Integrated Device Technology, Inc.
www.idt.com

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9